

# **ESF30SS120S**

## 30A, 1200V Hyperfast Diode

The EST30120 is a hyperfast diode with soft recovery characteristics (t<sub>rr</sub> < 65ns). It has half the recovery time of ultrafast diodes and is of silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of high frequency switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Formerly developmental type TA49041.

## Ordering Information

PART NUMBER	PACKAGE	BRAND
EST30120	TO-247	EST30120

NOTE: When ordering, use the entire part number.

## Symbol



### Features

Hyperfast with Soft Recovery	. <65ns
Operating Temperature	.175°C
Reverse Voltage	.1200V

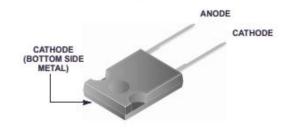
- · Avalanche Energy Rated
- · Planar Construction

## **Applications**

- · Switching Power Supplies
- · Power Switching Circuits
- General Purpose

## Packaging

JEDEC STYLE TO-247



Absolute Maximum Ratings T <sub>C</sub> = 25°C		
	RHRG30120	UNITS
Peak Repetitive Reverse VoltageVRRM	1200	V
Working Peak Reverse Voltage	1200	V
DC Blocking Voltage	1200	V
Average Rectified Forward Current	30	Α
(T <sub>C</sub> = 78°C)		
Repetitive Peak Surge Current IFRM	60	Α
(Square Wave, 20kHz)		
Nonrepetitive Peak Surge Current	300	Α
(Halfwave, 1 Phase, 60Hz)		
Maximum Power Dissipation	125	W
Avalanche Energy (See Figures 7 and 8)	30	mJ
Operating and Storage Temperature	-65 to 175	°C



<b>Electrical Specifications</b>	T <sub>C</sub> = 25°C, Unless Otherwise Specified
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SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V <sub>F</sub>	I <sub>F</sub> = 30A			3.2	V
	I <sub>F</sub> = 30A, T <sub>C</sub> = 150°C		(*)	2.6	V
I <sub>R</sub>	V <sub>R</sub> = 1200V			250	μА
	V <sub>R</sub> = 1200V, T <sub>C</sub> = 150°C		*	1	mA
t <sub>rr</sub>	I <sub>F</sub> = 1A, dI <sub>F</sub> /dt = 100A/μs		*	65	ns
	$I_F = 30A$ , $dI_F/dt = 100A/\mu s$		*	85	ns
ta	I <sub>F</sub> = 30A, dI <sub>F</sub> /dt = 100A/μs		48		ns
t <sub>b</sub>	I <sub>F</sub> = 30A, dI <sub>F</sub> /dt = 100A/μs		22		ns
R <sub>eJC</sub>		(4)	*	1.2	°C/W

### DEFINITIONS

V<sub>F</sub> = Instantaneous forward voltage (pw = 300μs, D = 2%).

IR = Instantaneous reverse current.

t<sub>rr</sub> = Reverse recovery time (See Figure 6), summation of t<sub>a</sub> + t<sub>b</sub>.

ta = Time to reach peak reverse current (See Figure 6).

tb = Time from peak IRM to projected zero crossing of IRM based on a straight line from peak IRM through 25% of IRM (See Figure 6).

R<sub>BJC</sub> = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

## Typical Performance Curves

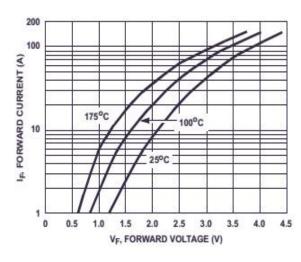


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

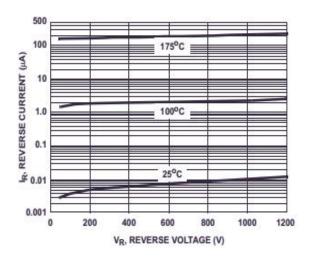


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE



## Typical Performance Curves (Continued)

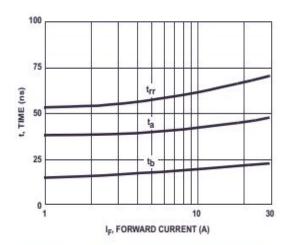


FIGURE 3. t<sub>rr</sub>, t<sub>a</sub> AND t<sub>b</sub> CURVES vs FORWARD CURRENT

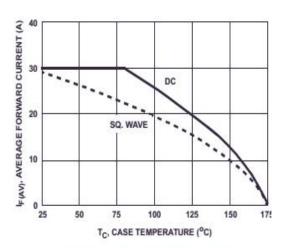


FIGURE 4. CURRENT DERATING CURVE

### Test Circuits and Waveforms

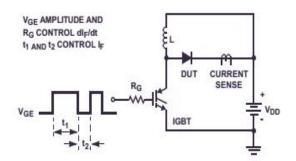


FIGURE 5. t<sub>rr</sub> TEST CIRCUIT

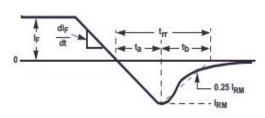


FIGURE 6. t<sub>rr</sub> WAVEFORMS AND DEFINITIONS

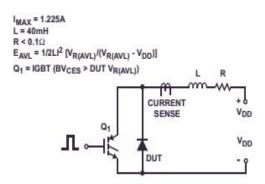


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

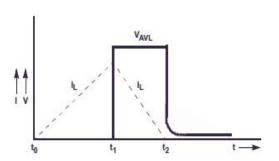


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



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